



STTA6006P STTA12006TV1/2

TURBOSWITCH™ ULTRA-FAST HIGH VOLTAGE DIODE

MAIN PRODUCT CHARACTERISTICS

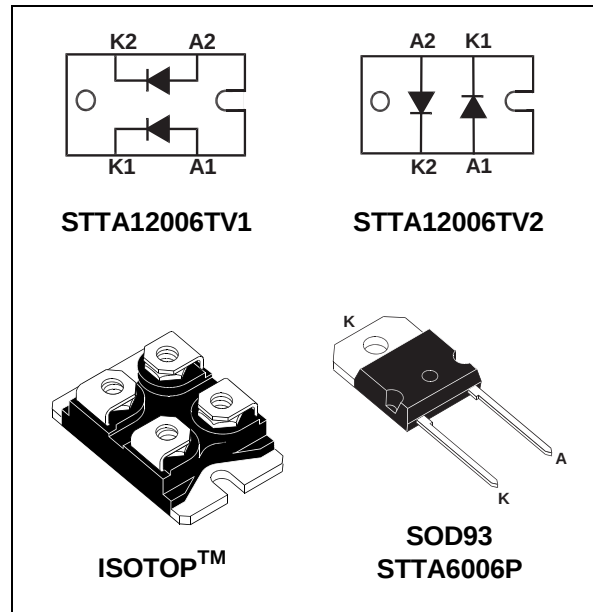
$I_{F(AV)}$	60A / 2 x 60A
V_{RRM}	600V
t_{rr} (typ)	45ns
V_F (max)	1.5V

FEATURES AND BENEFITS

- SPECIFIC TO "FREEWHEEL MODE" OPERATIONS: FREEWHEEL OR BOOSTER DIODE.
- ULTRA-FAST RECOVERY.
- VERY LOW OVERALL POWER LOSSES IN BOTH THE DIODE AND THE COMPANION TRANSISTOR.
- HIGH FREQUENCY OPERATIONS.
- INSULATED PACKAGE : ISOTOP
Electrical insulation : 2500V_{RMS}
Capacitance < 45 pF

DESCRIPTION

The TURBOSWITCH is a very high performance series of ultra-fast high voltage power diodes from 600V to 1200V. TURBOSWITCH family, drastically cuts losses in both the diode and the associated switching IGBT or MOSFET in all "freewheel mode" operations and is particularly suitable and efficient in motor



control freewheel applications and in booster diode applications in power factor control circuitries. Packaged either in ISOTOP or SOD93 these 600V devices are particularly intended for use on 240V domestic mains.

ABSOLUTE RATINGS (limiting values, per diode)

Symbol	Parameter		Value	Unit
V_{RRM}	Repetitive peak reverse voltage		600	V
V_{RSM}	Non repetitive peak reverse voltage		600	V
$I_{F(RMS)}$	RMS forward current	SOD93	80	A
		ISOTOP	150	A
I_{FRM}	Repetitive peak forward current	$t_p=5\mu s$ F=5kHz square	450	A
I_{FSM}	Surge non repetitive forward current	$t_p=10$ ms sinusoidal	500	A
T_j	Maximum operating junction temperature		150	°C
T_{stg}	Storage temperature range		-65 to 150	°C

TM : TURBOSWITCH is a trademark of STMicroelectronics

STTA12006TV1/2 / STTA6006P**THERMAL AND POWER DATA (Per diode)**

Symbol	Parameter	Test conditions		Value	Unit
$R_{th(j-c)}$	Junction to case thermal resistance	Per diode		0.85	°C/W
		Total		0.47	
		Coupling		0.1	
P_1	Conduction power dissipation $I_{F(AV)} = 60A$ $\delta = 0.5$	SOD93	$T_c = 64^\circ C$	108	W
		ISOTOP	$T_c = 58^\circ C$		
P_{max}	Total power dissipation $P_{max} = P_1 + P_3$ ($P_3 = 10\% P_1$)	SOD93	$T_c = 54^\circ C$	120	W
		ISOTOP	$T_c = 48^\circ C$		

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions		Min	Typ	Max	Unit
V_F^*	Forward voltage drop	$I_F = 60A$	$T_j = 25^\circ C$ $T_j = 125^\circ C$		1.25	1.75 1.5	V V
I_R^{**}	Reverse leakage current	$V_R = 0.8 \times V_{RRM}$	$T_j = 25^\circ C$ $T_j = 125^\circ C$		5	200 12	μA mA
V_{to}	Threshold voltage	$I_p < 3 \cdot I_{AV}$	$T_j = 125^\circ C$			1.14	V
r_d	Dynamic resistance					6	m Ω

Test pulses : * $t_p = 380 \mu s$, $\delta < 2\%$ ** $t_p = 5 ms$, $\delta < 2\%$

To evaluate the maximum conduction losses use the following equation :

$$P = V_{to} \times I_{F(AV)} + r_d \times I_F^2 (RMS)$$

DYNAMIC ELECTRICAL CHARACTERISTICS**TURN-OFF SWITCHING**

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
t_{rr}	Reverse recovery time	$T_j = 25^\circ C$ $I_F = 0.5 A$ $I_R = 1A$ $I_{rr} = 0.25A$ $I_F = 1 A$ $di_F/dt = -50A/\mu s$ $V_R = 30V$		45	80	ns
I_{RM}	Maximum reverse recovery current	$T_j = 125^\circ C$ $V_R = 400V$ $I_F = 60A$ $di_F/dt = -480 A/\mu s$ $di_F/dt = -500 A/\mu s$		24	38	A
S factor	Softness factor	$T_j = 125^\circ C$ $V_R = 400V$ $I_F = 60A$ $di_F/dt = -500 A/\mu s$		0.37		/

TURN-ON SWITCHING

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
t_{fr}	Forward recovery time	$T_j = 25^\circ C$ $I_F = 60 A$, $di_F/dt = 480 A/\mu s$ measured at, $1.1 \times V_{Fmax}$			700	ns
V_{Fp}	Peak forward voltage	$T_j = 25^\circ C$ $I_F = 60A$, $di_F/dt = 480 A/\mu s$			14	V

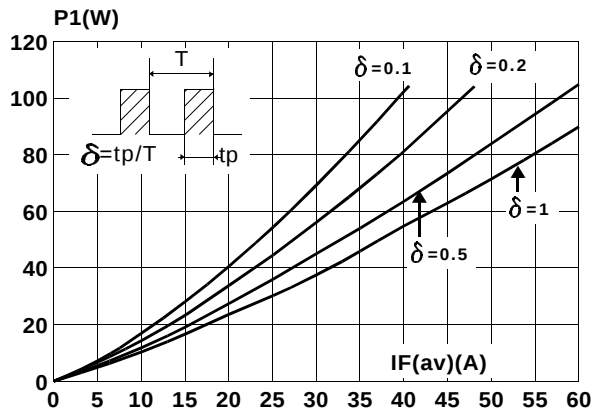
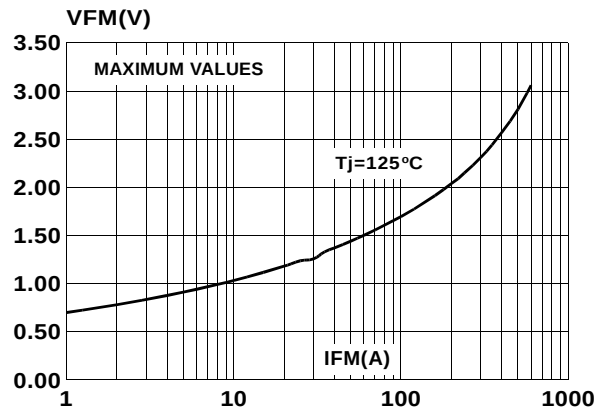
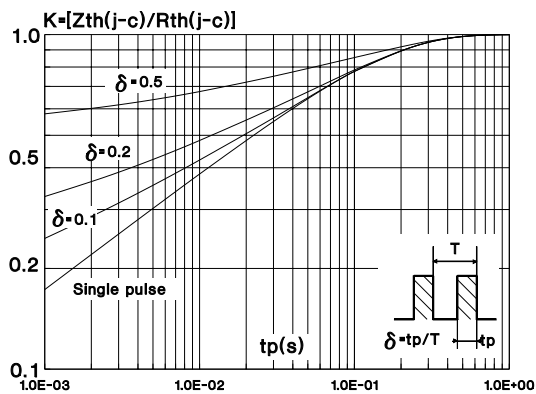
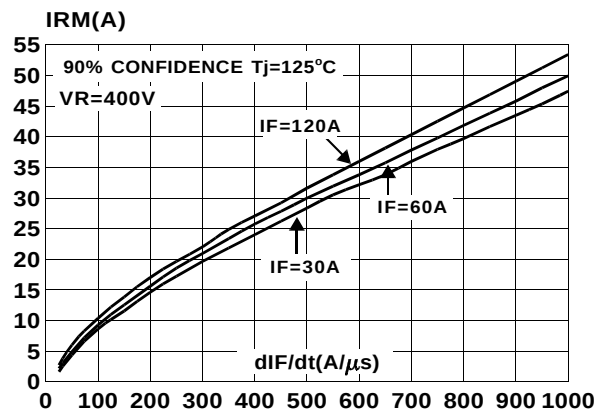
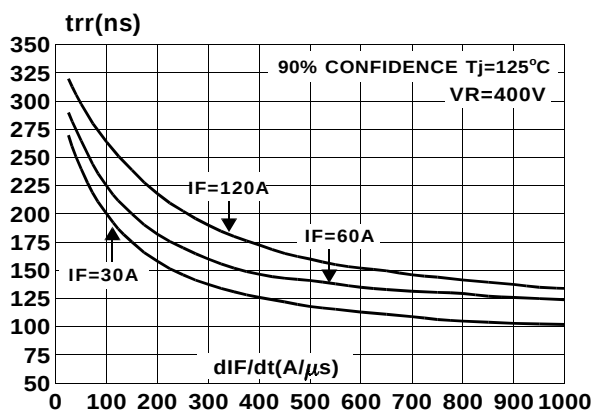
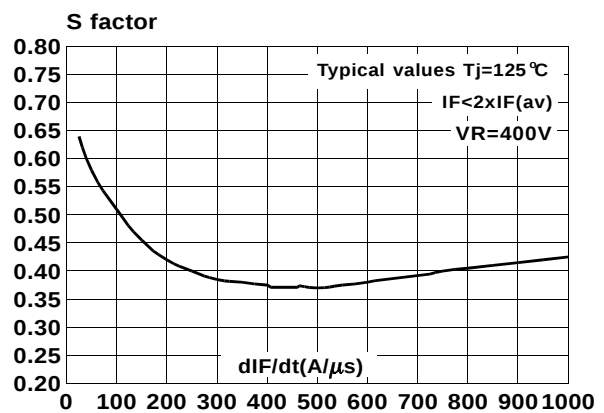
Fig. 1: Conduction losses versus average current.**Fig. 2:** Forward voltage drop versus forward current.**Fig. 3:** Relative variation of thermal transient impedance junction to case versus pulse duration.**Fig. 4:** Peak reverse recovery current versus dI_F/dt .**Fig. 5:** Reverse recovery time versus dI_F/dt .**Fig. 6:** Softness factor (tb/ta) versus dI_F/dt .

Fig. 7: Relative variation of dynamic parameters versus junction temperature (reference $T_j=125^{\circ}\text{C}$).

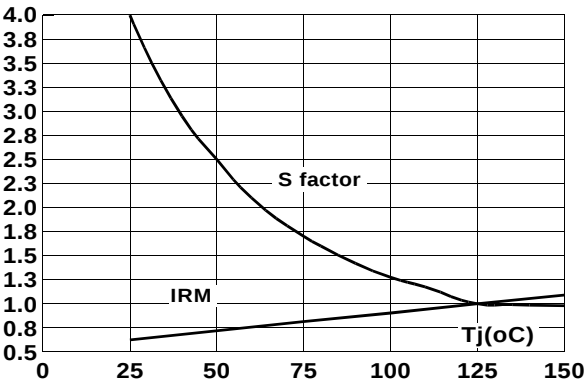


Fig. 8: Transient peak forward voltage versus dI_F/dt .

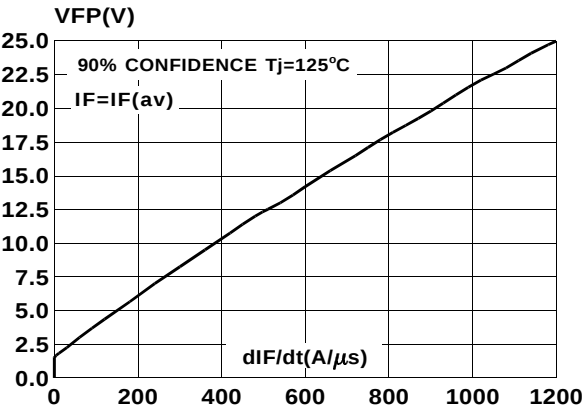
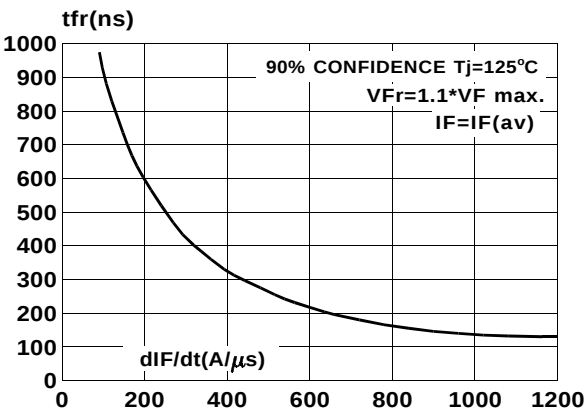


Fig. 9: Forward recovery time versus dI_F/dt .



APPLICATION DATA

The TURBOSWITCH is especially designed to provide the lowest overall power losses in any "FREEWHEEL Mode" application (Fig.A) considering both the diode and the companion

transistor, thus optimizing the overall performance in the end application. The way of calculating the power losses is given below:

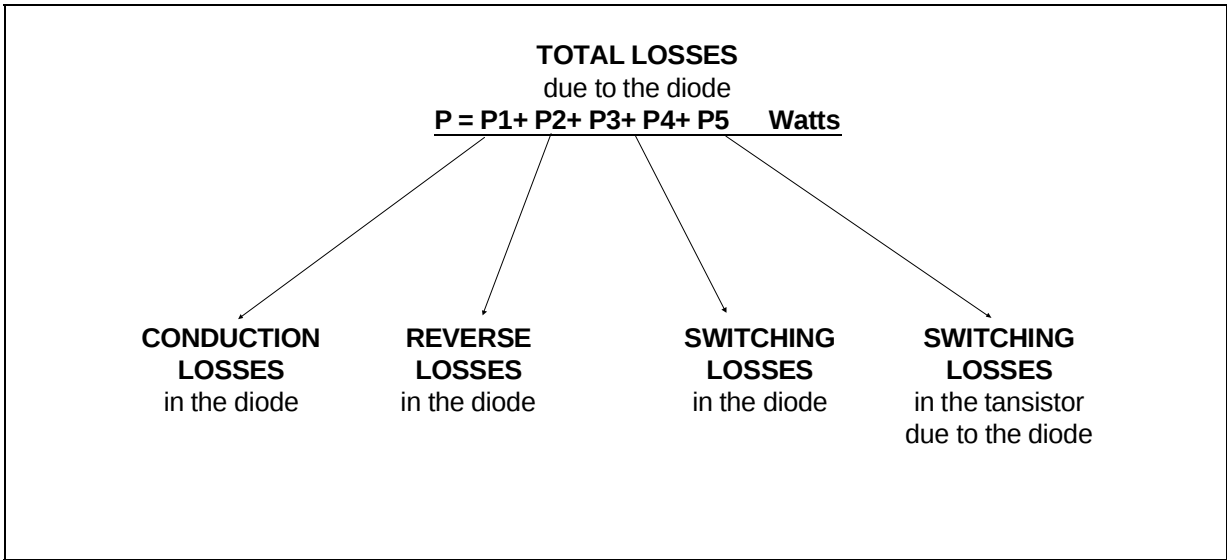
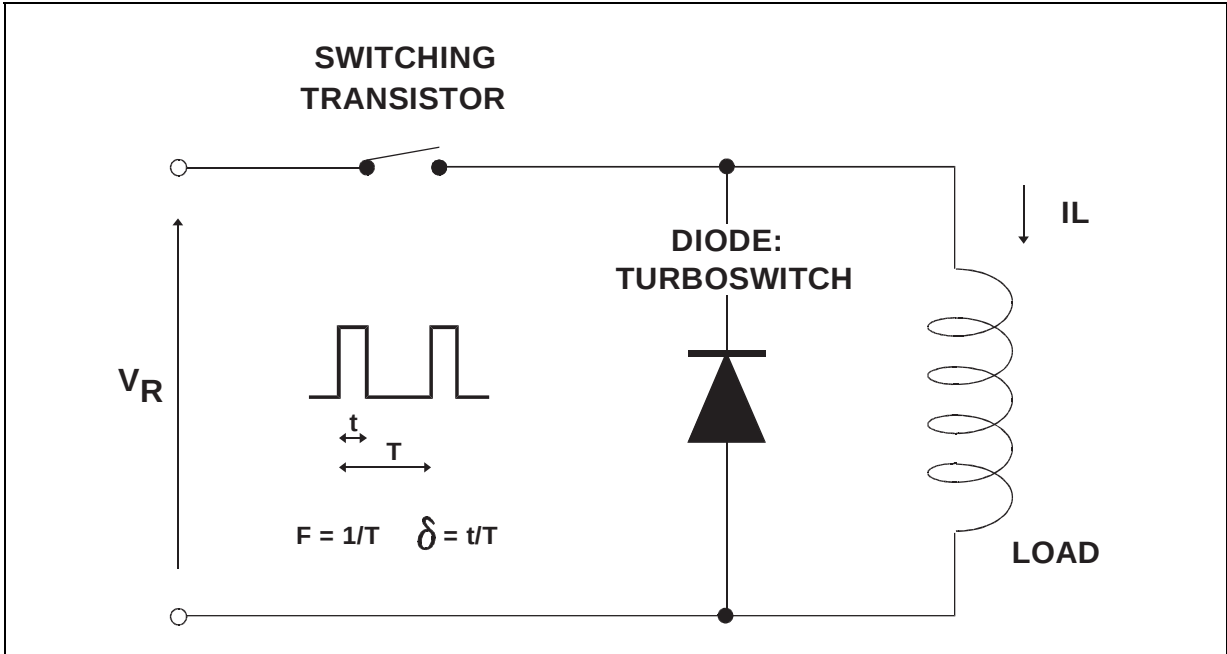
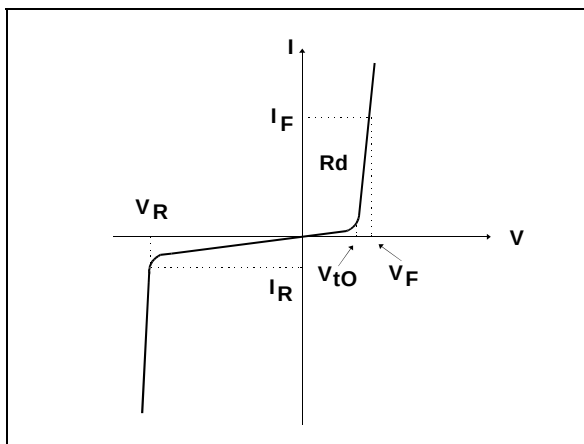


Fig. A : "FREEWHEEL" MODE.



APPLICATION DATA (Cont'd)

Fig. B: STATIC CHARACTERISTICS



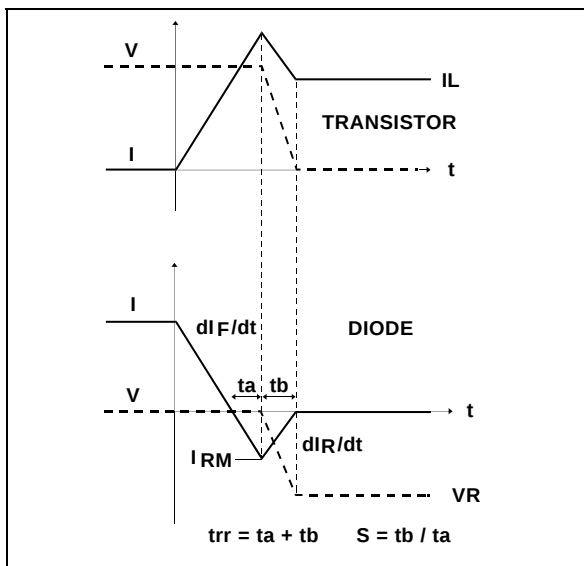
Conduction losses :

$$P1 = V_{t0} \cdot I_F(AV) + R_d \cdot I_F^2(RMS)$$

Reverse losses :

$$P2 = V_R \cdot I_R \cdot (1 - \delta)$$

Fig. C: TURN-OFF CHARACTERISTICS



Turn-on losses :

(in the transistor, due to the diode)

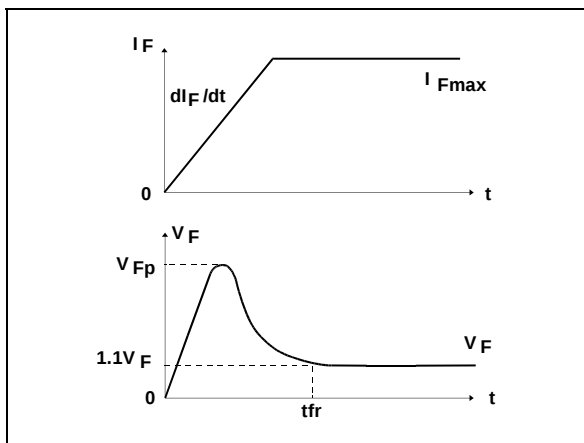
$$P5 = \frac{V_R \times I_{RM}^2 \times (3 + 2 \times S) \times F}{6 \times dI_F/dt} + \frac{V_R \times I_{RM} \times I_L \times (S + 2) \times F}{2 \times dI_F/dt}$$

Turn-off losses (in the diode) :

$$P3 = \frac{V_R \times I_{RM}^2 \times S \times F}{6 \times dI_F/dt}$$

P3 and P5 are suitable for power MOSFET and IGBT

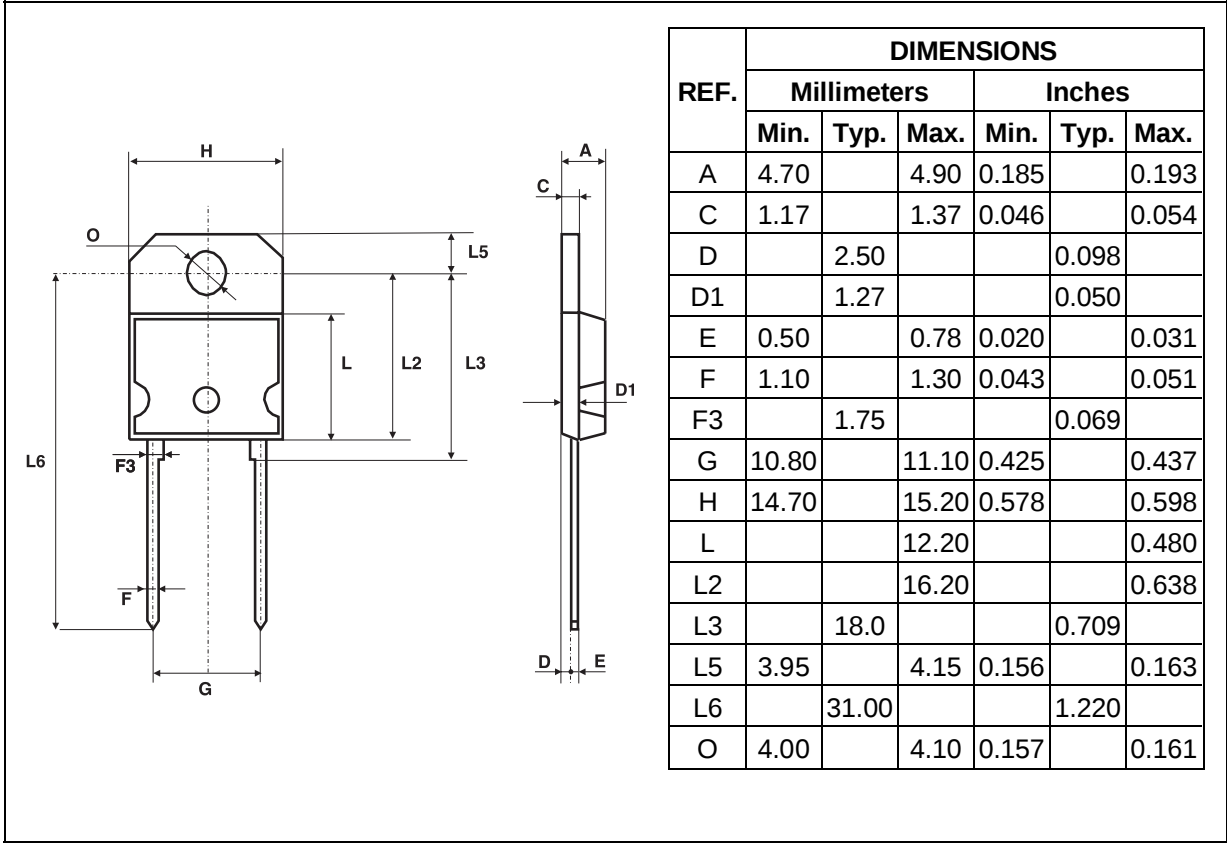
Fig. D: TURN-ON CHARACTERISTICS



Turn-on losses :

$$P4 = 0.4 (V_{FP} - V_F) \cdot I_{Fmax} \cdot t_{fr} \cdot F$$

PACKAGE MECHANICAL DATA
SOD93



Cooling method : by conduction (C)
Recommended torque value : 0.8 m.N
Maximum torque value : 1m.N

STTA12006TV1/2 / STTA6006P**PACKAGE MECHANICAL DATA**
ISOTOP

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	11.80	12.20	0.465	0.480
A1	8.90	9.10	0.350	0.358
B	7.8	8.20	0.307	0.323
C	0.75	0.85	0.030	0.033
C2	1.95	2.05	0.077	0.081
D	37.80	38.20	1.488	1.504
D1	31.50	31.70	1.240	1.248
E	25.15	25.50	0.990	1.004
E1	23.85	24.15	0.939	0.951
E2	24.80 typ.		0.976 typ.	
G	14.90	15.10	0.587	0.594
G1	12.60	12.80	0.496	0.504
G2	3.50	4.30	0.138	0.169
F	4.10	4.30	0.161	0.169
F1	4.60	5.00	0.181	0.197
P	4.00	4.30	0.157	0.69
P1	4.00	4.40	0.157	0.173
S	30.10	30.30	1.185	1.193

Cooling method : by conduction (C)

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STTA6006P	STTA6006P	SOD93	3.79g	30	Tube
STTA12006TV1	STTA12006TV1	ISOTOP	27g without screws	10	Tube
STTA12006TV2	STTA12006TV2	ISOTOP		10	Tube

■ Epoxy meets UL94,V0

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